

RoHS

COMPLIANT HALOGEN

Available

Vishay Siliconix

## N-Channel 30-V (D-S) MOSFET

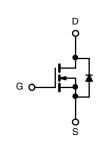
PRODUCT SUMMARY						
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)			
30	0.023 at V <sub>GS</sub> = 10 V	8				
	0.025 at V <sub>GS</sub> = 4.5 V	7.5	6.5			
	0.030 at V <sub>GS</sub> = 3.0 V	6.8	0.5			
	0.036 at V <sub>GS</sub> = 2.5 V	6.0				



- Halogen-free According to IEC 61249-2-21
  Available
- TrenchFET<sup>®</sup> Gen II Power MOSFET
- 100 % R<sub>g</sub> Tested

#### **APPLICATIONS**

- High-Side DC/DC Conversion
  - Notebook
  - Desktop
  - Server
- Notebook Logic DC/DC, Low-Side



SO-8 S 8 D S D 7 2 S 6 D З G D 5 Top View

Ordering Information: Si4346DY-T1-E3 (Lead (Pb)-free) Si4346DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

<b>ABSOLUTE MAXIMUM RATINGS</b> $T_A = 25 \degree C$ , unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	:	30	V	
Gate-Source Voltage		V <sub>GS</sub>	± 12		v	
	T <sub>A</sub> = 25 °C	I <sub>D</sub>	8	5.9		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		6.5	4.7		
Pulsed Drain Current		I <sub>DM</sub>	30		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	2.2	1.20		
	T <sub>A</sub> = 25 °C	PD	2.5	1.31	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	ГD	1.6	0.84	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55	to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 s	- R <sub>thJA</sub>	43	50	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		74	95		
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	22	27		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	0.7		2.0	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA	
Zaus Cata Maltaga Dusia Cumunat	I <sub>DSS</sub>	$V_{DS} = 30 V, V_{GS} = 0 V$			1	μA	
Zero Gate Voltage Drain Current		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$			5		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	20			Α	
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 8 \text{ A}$		0.019	0.023		
	D	$V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A}$		0.021	0.025	Ω	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 3.0 \text{ V}, \text{ I}_{D} = 6.8 \text{ A}$		0.023	0.030		
		$V_{GS} = 2.5 \text{ V}, I_D = 6.0 \text{ A}$		0.027	0.036		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 8 \text{ A}$		32		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{S} = 2.2 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.1	V	
Dynamic <sup>b</sup>				•			
Total Gate Charge	Qg			6.5	10		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 8 \text{ A}$		2.3		nC	
Gate-Drain Charge	Q <sub>gd</sub>			1.1			
Gate Resistance	Rg		0.25	0.5	0.75	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			9	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 15 $\Omega$		11	17		
Turn-Off Delay Time	t <sub>d(off)</sub>	$t_{d(off)}$ I <sub>D</sub> $\cong$ 1 A, V <sub>GEN</sub> = 10 V, R <sub>g</sub> = 6 $\Omega$		40	60	ns	
Fall Time	t <sub>f</sub>			7	11		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.2 A, dl/dt = 100 A/μs		20	35		

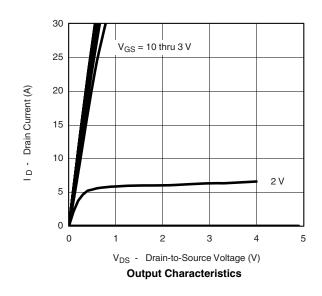
Notes:

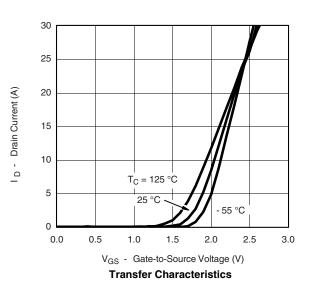
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

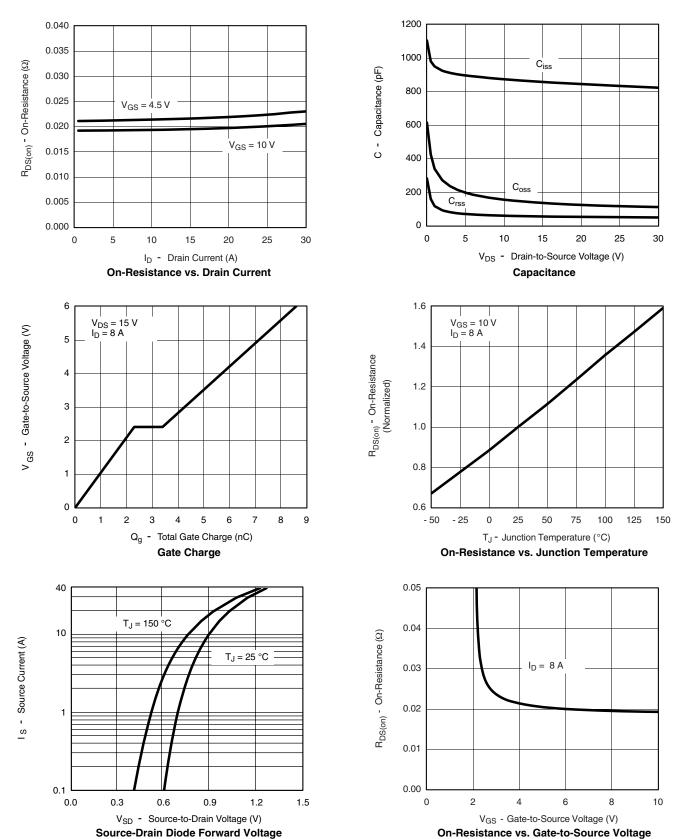
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Si4346DY Vishay Siliconix



### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

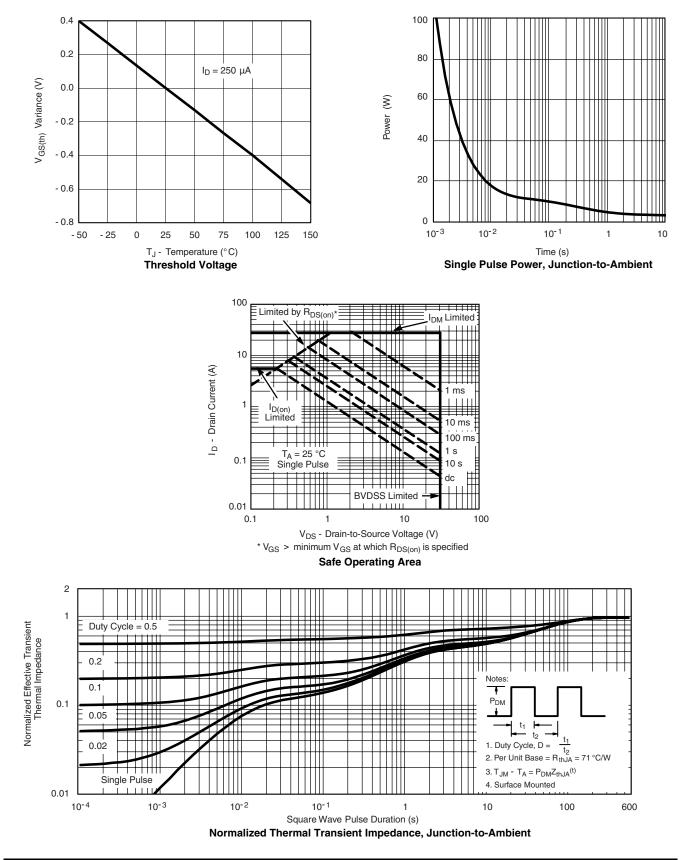
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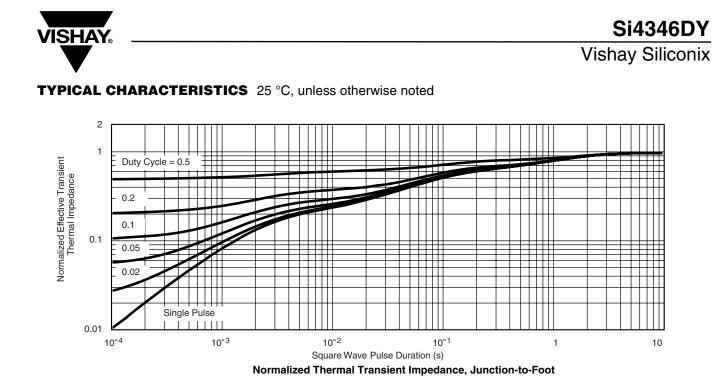
## Si4346DY

## Vishay Siliconix









Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?72958">www.vishay.com/ppg?72958</a>.



# Package Information

Vishay Siliconix

# SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INCHES			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050	0 BSC		
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

# **Application Note 826**

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**RECOMMENDED MINIMUM PADS FOR SO-8** 



Recommended Minimum Pads Dimensions in Inches/(mm)

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